

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	89472	((phase near chang\$3) chalcogenide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 06:58
L2	166	1 and ((pad strip) near substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 07:15
L3	38	2 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 07:15
L4	18911	1 and memory	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 07:15
L5	635	4 and ((dielectric insulat\$3 SiO SiN SiON) near substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 07:16
L6	85	5 and ((bottom lower) near electrode\$1) with ((upper top) near electrode\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/30 07:17